# NSN 5962-01-173-8027

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## **Body Length:**

Between 1.235 inches and 1.285 inches

# Body Width:

Between 0.515 inches and 0.600 inches

# **Body Height:**

0.217 inches

# **Maximum Power Dissipation Rating:**

1.8 watts

### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

## Storage Tempurature Range:

-65.0/+150.0 degrees celsius

## **Features Provided:**

Hermetically sealed and burn in and programmable and ultraviolet erasable and w/enable

### Inclosure Material:

Ceramic

## Inclosure Configuration:

Dual-in-line

## **Output Logic Form:**

N-type metal oxide-semiconductor logic

## Input Circuit Pattern:

11 input

# **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

-0.3 volts power source and 20.0 volts power source

## **Time Rating Per Chacteristic:**

450.00 nanoseconds propagation delay time, low to high level output and 450.00 nanoseconds propagation delay time, high to low level output

## Memory Device Type:

Eprom

## **Memory Capacity:**

Unknown

## Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

## Terminal Type And Quantity:

24 printed circuit

#### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

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